

Table 11: AC Parameters (Die)

Symbol	Characteristic	Min <sup>(2)</sup>	Typ <sup>(1)</sup>	Max <sup>(2)</sup>	Units	Conditions
F <sub>S</sub>	Sampling Frequency	ISD4003-04M	8.0		KHz	(5)
		ISD4003-05M	6.4		KHz	(5)
		ISD4003-06M	5.3		KHz	(5)
		ISD4003-08M	4.0		KHz	(5)
F <sub>CF</sub>	Filter Pass Band	ISD4003-04M	3.4		KHz	3dB Roll-Off Point <sup>(3) (6)</sup>
		ISD4003-05M	2.7		KHz	3dB Roll-Off Point <sup>(3) (6)</sup>
		ISD4003-06M	2.3		KHz	3dB Roll-Off Point <sup>(3) (6)</sup>
		ISD4003-08M	1.7		KHz	3dB Roll-Off Point <sup>(3) (6)</sup>
T <sub>REC</sub>	Record Duration	ISD4003-04M	4		min	(5)
		ISD4003-05M	5		min	(5)
		ISD4003-06M	6		min	(5)
		ISD4003-08M	8		min	(5)
T <sub>PLAY</sub>	Playback Duration	ISD4003-04M	4		min	(5)
		ISD4003-05M	5		min	(5)
		ISD4003-06M	6		min	(5)
		ISD4003-08M	8		min	(5)
T <sub>PUD</sub>	Power-Up Delay	ISD4003-04M	25		msec	
		ISD4003-05M	31.25		msec	
		ISD4003-06M	37.5		msec	
		ISD4003-08M	50		msec	
T <sub>STOP</sub> OR T <sub>PAUSE</sub>	Stop or Pause in Record or Play	ISD4003-04M	50		msec	
		ISD4003-05M	62.5		msec	
		ISD4003-06M	75		msec	
		ISD4003-08M	100		msec	
T <sub>RAC</sub>	RAC Clock Period	ISD4003-04M	200		msec	(9)
		ISD4003-05M	250		msec	(9)
		ISD4003-06M	300		msec	(9)
		ISD4003-08M	400		msec	(9)
T <sub>RACLO</sub>	RAC Clock Low Time	ISD4003-04M	25		msec	
		ISD4003-05M	31.25		msec	
		ISD4003-06M	37.5		msec	
		ISD4003-08M	50		msec	
T <sub>RACM</sub>	RAC Clock Period in Message Cueing Mode	ISD4003-04M	125		μsec	
		ISD4003-05M	156.3		μsec	
		ISD4003-06M	187.5		μsec	
		ISD4003-08M	250		μsec	
T <sub>RACML</sub>	RAC Clock Low Time in Message Cueing Mode	ISD4003-04M	15.63		μsec	
		ISD4003-05M	19.53		μsec	
		ISD4003-06M	23.44		μsec	
		ISD4003-08M	31.25		μsec	

**Table 11: AC Parameters (Die)**

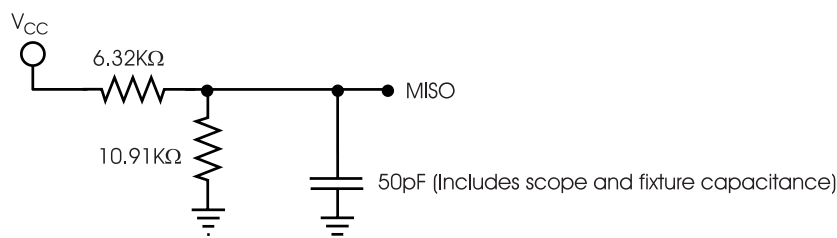
Symbol	Characteristic	Min <sup>(2)</sup>	Typ <sup>(1)</sup>	Max <sup>(2)</sup>	Units	Conditions
THD	Total Harmonic Distortion		1	2	%	@ 1 KHz
V <sub>IN</sub>	ANA IN Input Voltage			32	mV	Peak-to-Peak <sup>4,7,8</sup>

1. Typical values:  $T_A = 25^\circ\text{C}$  and 3.0 V.
2. All min/max limits are guaranteed by ISD via electrical testing or characterization. Not all specifications are 100 percent tested.
3. Low-frequency cut off depends upon the value of external capacitors (see Pin Descriptions).
4. Single-ended input mode. In the differential input mode, V<sub>IN</sub> maximum for ANA IN+ and ANA IN- is 16 mV peak-to-peak.
5. Sampling Frequency and Duration can vary as much as  $\pm 2.25$  percent over the commercial temperature and voltage ranges. For greater stability, an external clock can be utilized (see Pin Descriptions).
6. Filter specification applies to the antialiasing filter and to the smoothing filter.
7. The typical output voltage will be approximately 570 mV peak-to-peak with V<sub>IN</sub> at 32 mV peak-to-peak.
8. For optimal signal quality, this maximum limit is recommended.
9. When a record command is sent,  $T_{RAC} = T_{RAC} + T_{RACLO}$  on the first row addressed.

**Table 12: SPI AC Parameters<sup>1</sup>**

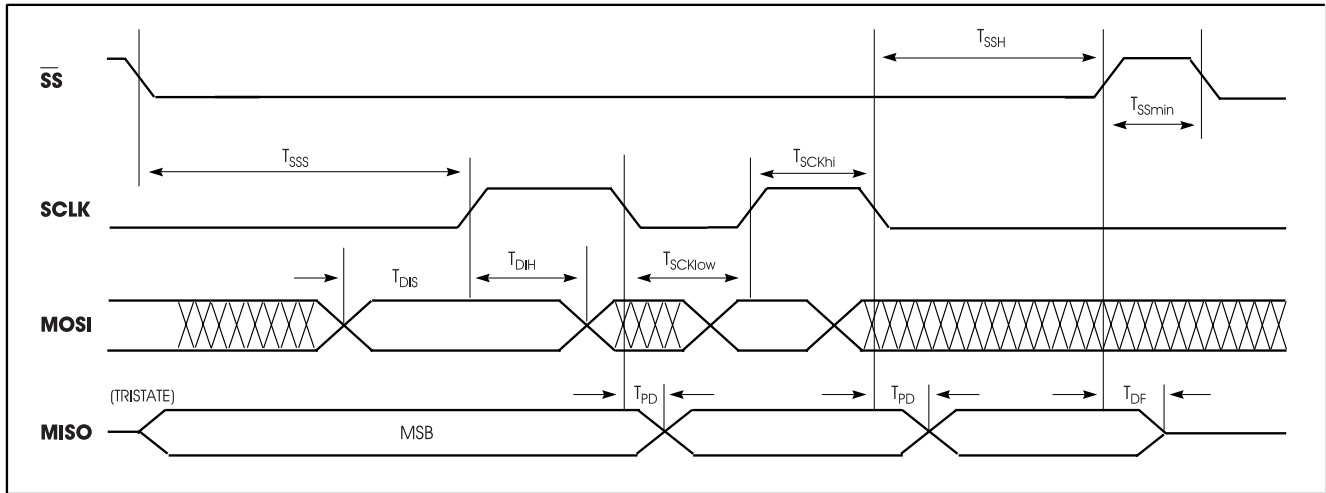
Symbol	Characteristics	Min	Max	Units	Conditions
T <sub>SSS</sub>	$\overline{SS}$ Setup Time	500		nsec	
T <sub>SSH</sub>	$\overline{SS}$ Hold Time	500		nsec	
T <sub>DIS</sub>	Data in Setup Time	200		nsec	
T <sub>DIH</sub>	Data in Hold Time	200		nsec	
T <sub>PD</sub>	Output Delay		500	nsec	
T <sub>DF</sub> <sup>(2)</sup>	Output Delay to hiZ		500	nsec	
T <sub>SSmin</sub>	$\overline{SS}$ HIGH	1		$\mu\text{sec}$	
T <sub>SCKhi</sub>	SCLK High Time	400		nsec	
T <sub>SCKlow</sub>	SCLK Low Time	400		nsec	
F <sub>0</sub>	CLK Frequency		1,000	KHz	

1. Typical values:  $T_A = 25^\circ\text{C}$  and 3.0 V. Timing measured at 50 percent of the V<sub>CC</sub> level.
2. Tristate test condition.

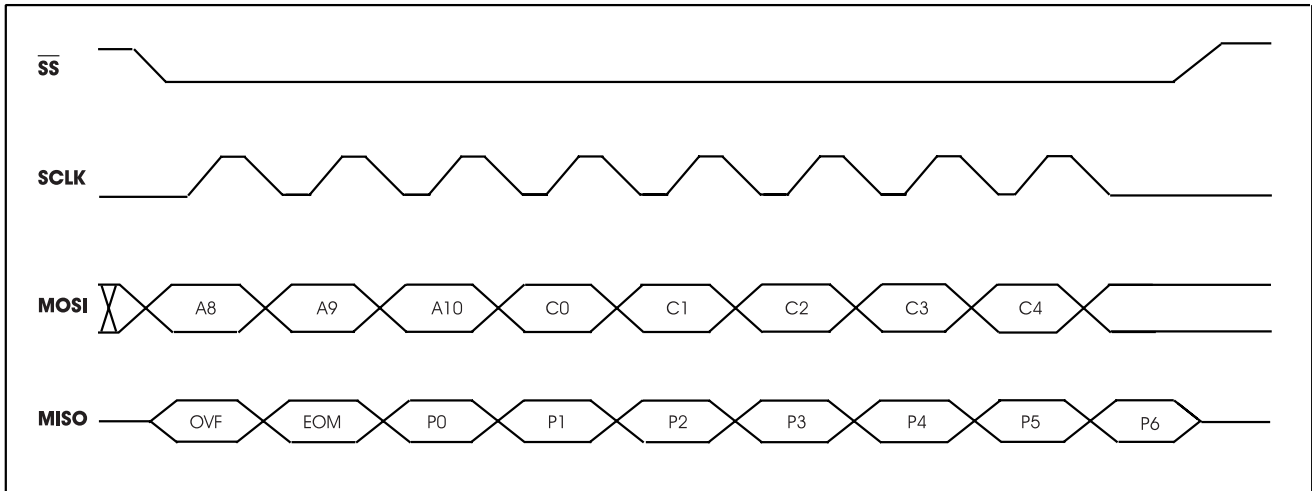


**TIMING DIAGRAMS**

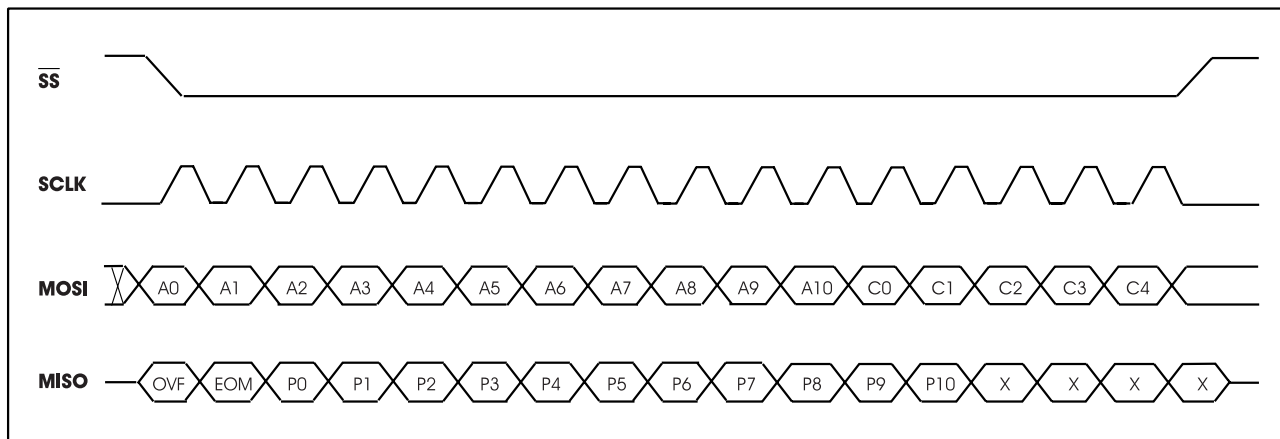
**Figure 6: Timing Diagram**



**Figure 7: 8-Bit Command Format**



**Figure 8: 16-Bit Command Format**



**Figure 9: Playback/Record and Stop Cycle**

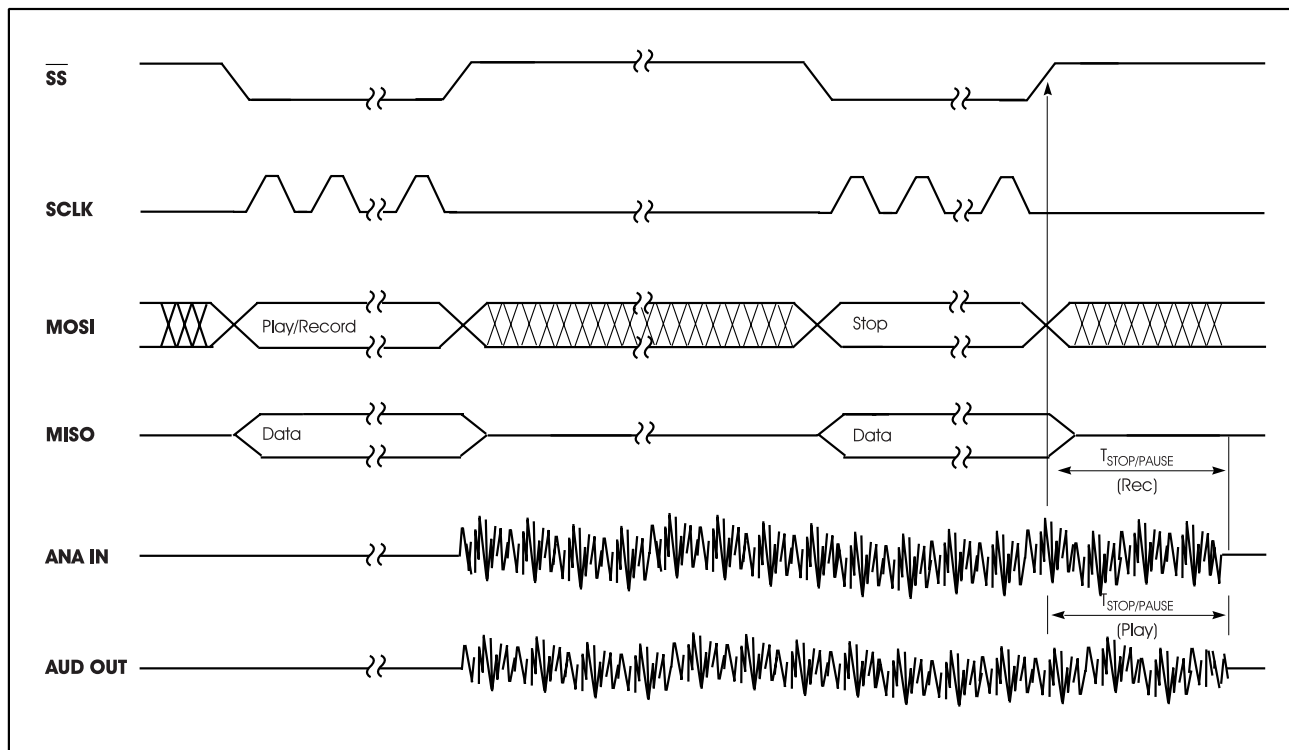
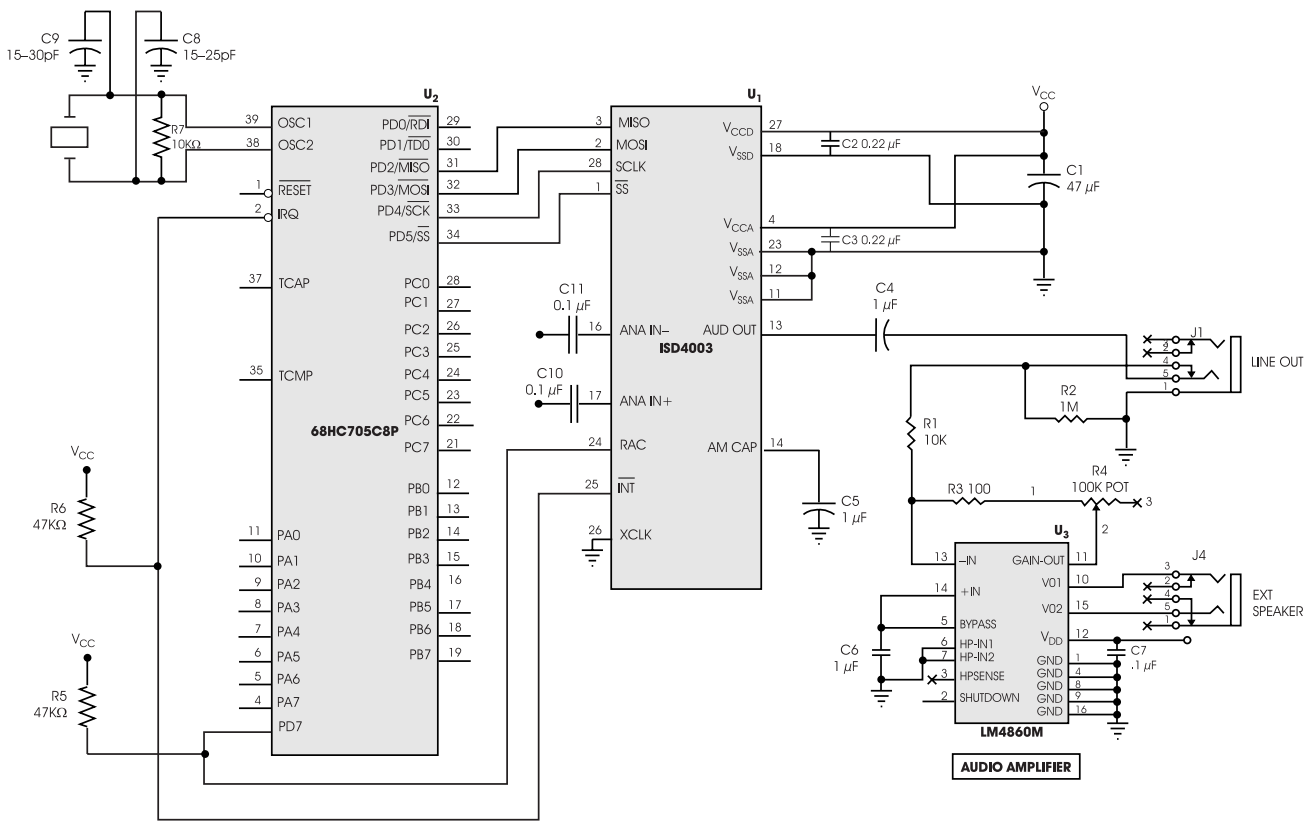
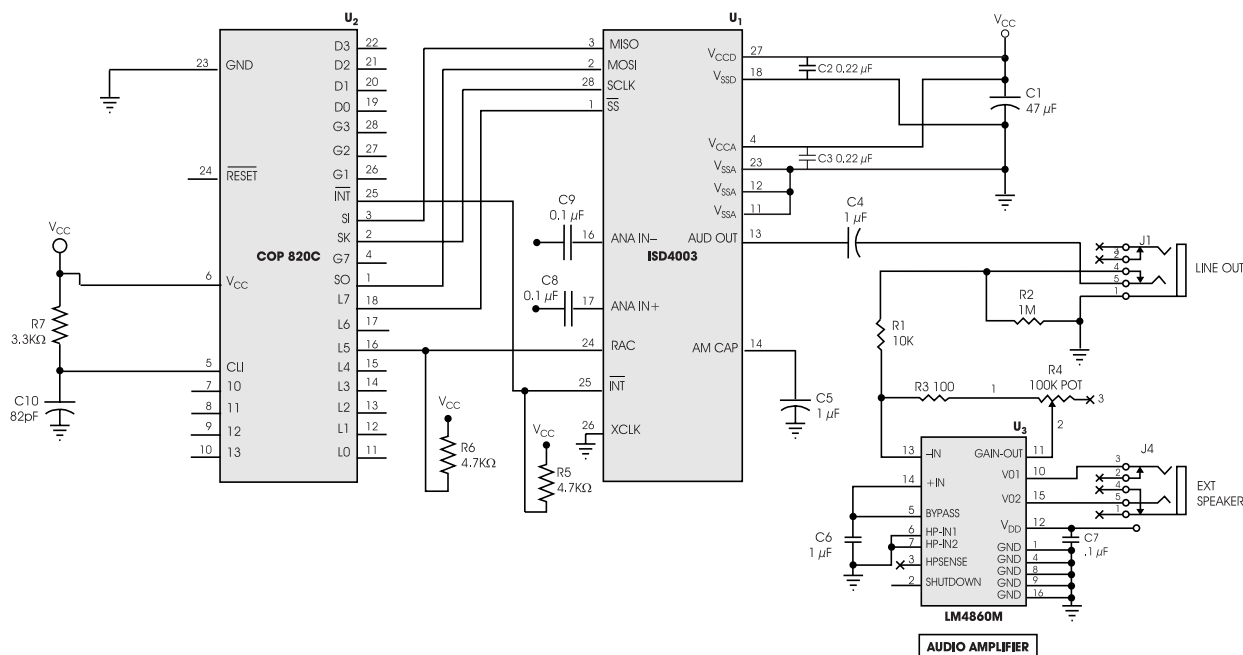


Figure 10: Application Example Using SPI<sup>(1)</sup>



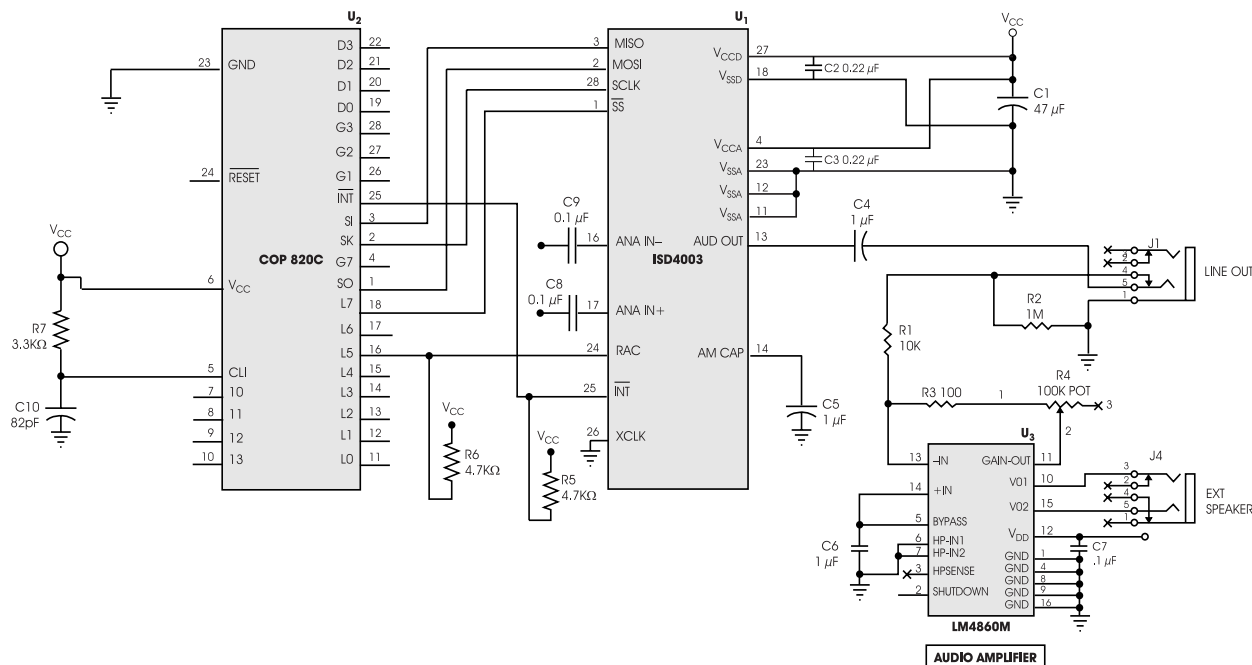
1. This application example is for illustration purposes only. ISD makes no representation or warranty that such application will be suitable for production.
2. Please make sure the bypass capacitor, C2 is as close as possible to the package.

**Figure 11: Application Example Using Microwire<sup>(1)</sup>**



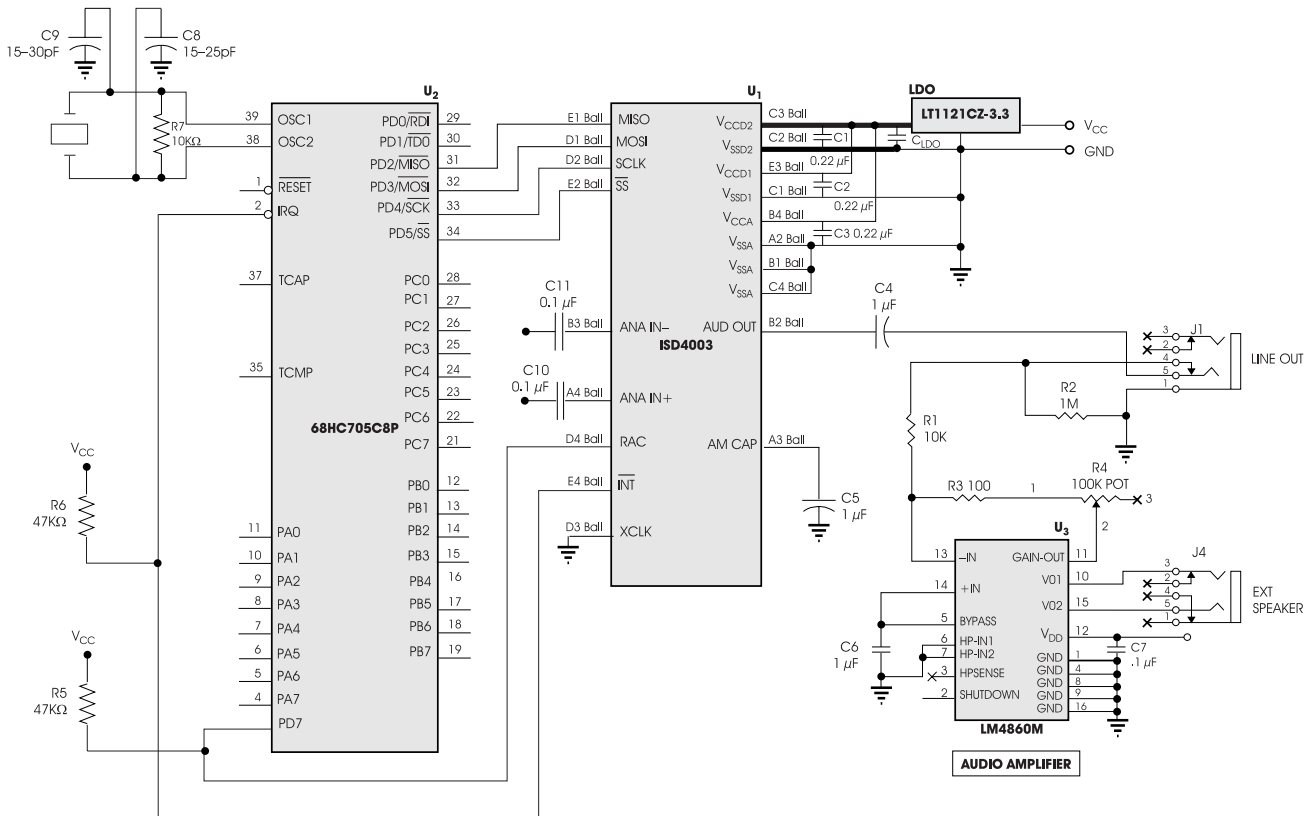
1. This application example is for illustration purposes only. ISD makes no representation or warranty that such application will be suitable for production.
2. Please make sure the bypass capacitor, C2 is as close as possible to the package.

**Figure 12: Application Example Using SPI Port on Microcontroller<sup>(1)</sup>**



1. This application example is for illustration purposes only. ISD makes no representation or warranty that such application will be suitable for production.
2. Please make sure the bypass capacitor, C2 is as close as possible to the package.

Figure 13: Application Example Using SPI with a Chip Scale Packaged Device



1. This application example is for illustration purposes only. ISD makes no representation or warranty that such application will be suitable for production.
2. Please make sure all bypass capacitors are as close as possible to the package.
3. Ground plane must be used to connect all  $V_{SSA}$  pins together. If a ground plane is not available then a short and low impedance path is necessary.
4. Route ANA IN+ and ANA IN- away from  $V_{CCD}$  and  $V_{SSD}$  return paths.
5. Biasing for electret microphone must come from  $V_{CCA}$  and  $V_{SSA}$ .
6. AMCAP must return to  $V_{SSA}$ .
7. Traces from  $V_{CCD2}$  to the LDO (Low Dropout regulator) and from  $V_{SSD2}$  to the LDO ground should be as thick as possible. The distance between these two traces should be as short as possible.

## DEVICE PHYSICAL DIMENSIONS

Figure 14: 28-Lead 8x13.4 mm Plastic Thin Small Outline Package (TSOP) Type I (E)

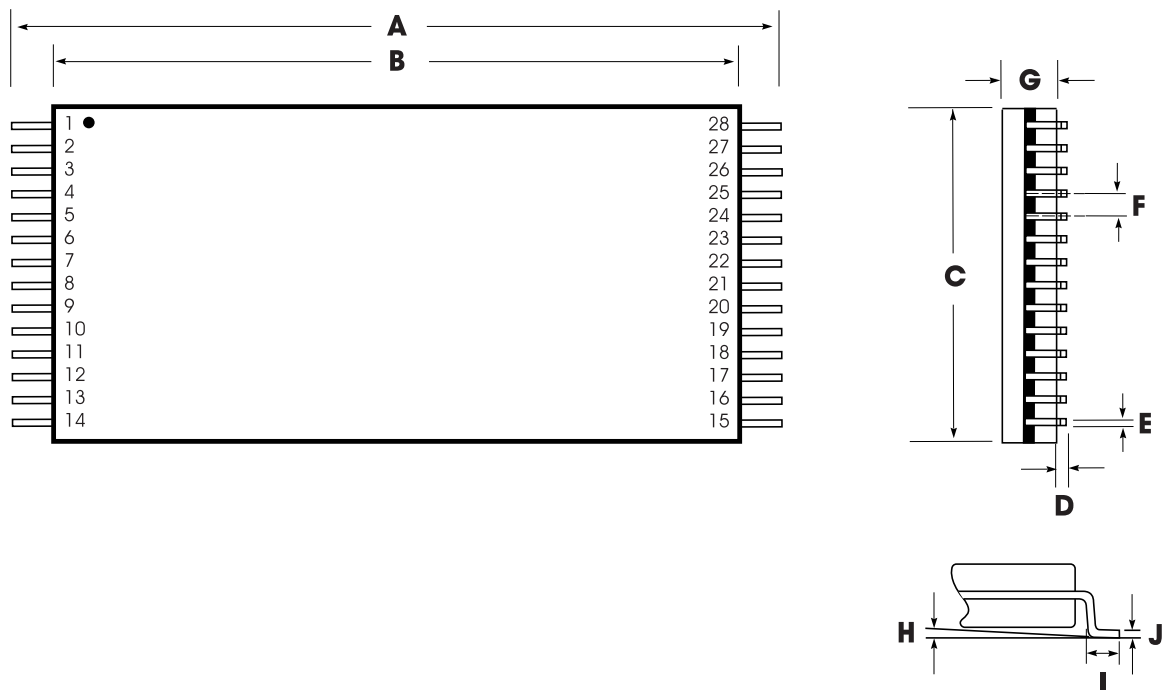


Table 13: Plastic Thin Small Outline Package (TSOP) Type I (E) Dimensions

	INCHES			MILLIMETERS		
	Min	Nom	Max	Min	Nom	Max
A	0.520	0.528	0.535	13.20	13.40	13.60
B	0.461	0.465	0.469	11.70	11.80	11.90
C	0.311	0.315	0.319	7.90	8.00	8.10
D	0.002		0.006	0.05		0.15
E	0.007	0.009	0.011	0.17	0.22	0.27
F		0.0217			0.55	
G	0.037	0.039	0.041	0.95	1.00	1.05
H	0°	3°	6°	0°	3°	6°
I	0.020	0.022	0.028	0.50	0.55	0.70
J	0.004		0.008	0.10		0.21

**NOTE:** Lead coplanarity to be within 0.004 inches.



Figure 15: 28-Lead 0.600-Inch Plastic Dual Inline Package (PDIP) (P)

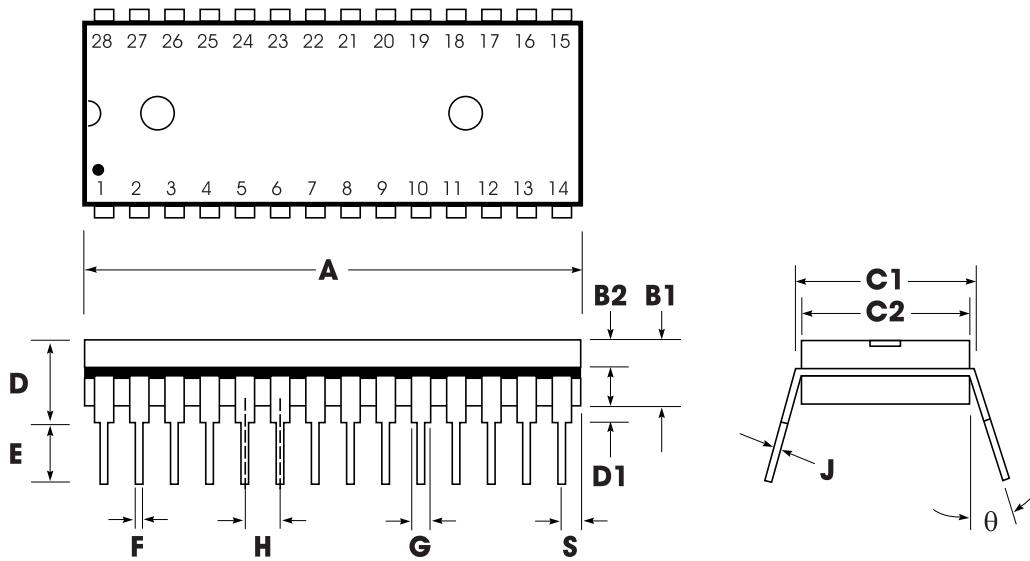
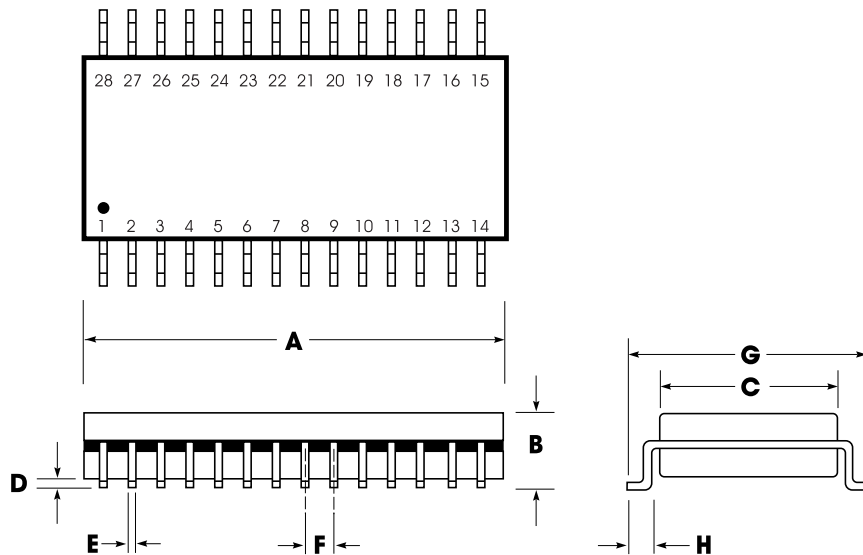


Table 14: Plastic Dual Inline Package (PDIP) (P) Dimensions

	INCHES			MILLIMETERS		
	Min	Nom	Max	Min	Nom	Max
A	1.445	1.450	1.455	36.70	36.83	36.96
B1		0.150			3.81	
B2	0.065	0.070	0.075	1.65	1.78	1.91
C1	0.600		0.625	15.24		15.88
C2	0.530	0.540	0.550	13.46	13.72	13.97
D			0.19			4.83
D1	0.015			0.38		
E	0.125		0.135	3.18		3.43
F	0.015	0.018	0.022	0.38	0.46	0.56
G	0.055	0.060	0.065	1.40	1.52	1.65
H		0.100			2.54	
J	0.008	0.010	0.012	0.20	0.25	0.30
S	0.070	0.075	0.080	1.78	1.91	2.03
q	0°		15°	0°		15°

**Figure 16: 28-Lead 0.300-Inch Plastic Small Outline Integrated Circuit (SOIC) (S)**



**Table 15: Plastic Small Outline Integrated Circuit (SOIC) (S) Dimensions**

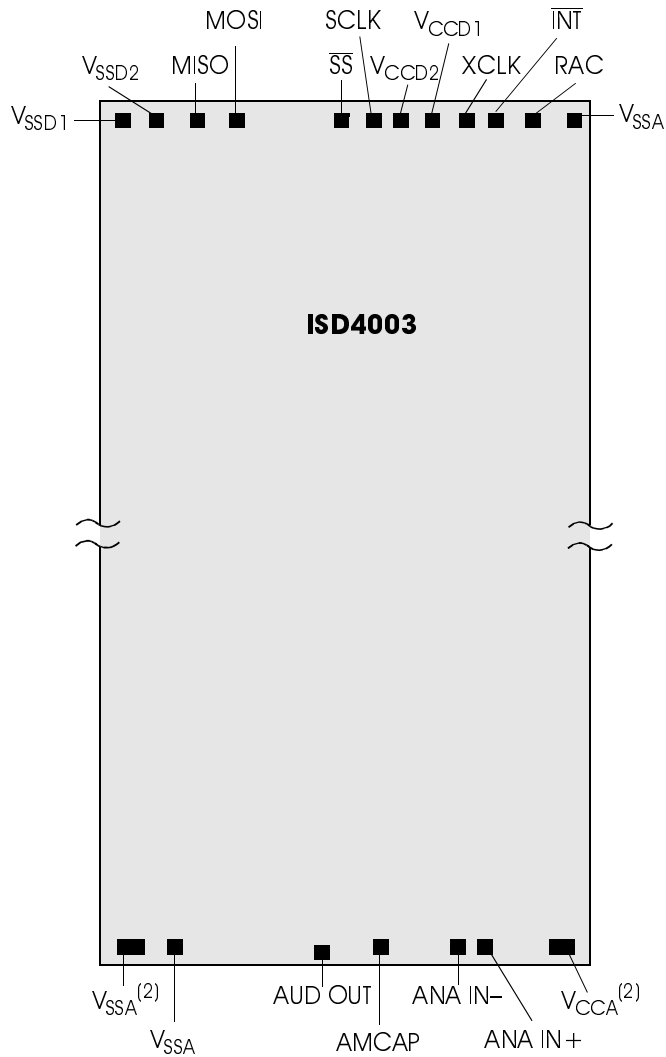
	INCHES			MILLIMETERS		
	Min	Nom	Max	Min	Nom	Max
A	0.701	0.706	0.711	17.81	17.93	18.06
B	0.097	0.101	0.104	2.46	2.56	2.64
C	0.292	0.296	0.299	7.42	7.52	7.59
D	0.005	0.009	0.0115	0.127	0.22	0.29
E	0.014	0.016	0.019	0.35	0.41	0.48
F		0.050			1.27	
G	0.400	0.406	0.410	10.16	10.31	10.41
H	0.024	0.032	0.040	0.61	0.81	1.02

**NOTE:** Lead coplanarity to be within 0.004 inches.

Figure 17: ISD4003 Series Bonding Physical Layout<sup>1</sup> (Unpackaged Die)

**ISD4003 Series**

- I. Die Dimensions  
X: 166.6 ±1 mils  
Y: 274.9 ±1 mils
- II. Die Thickness  
11.5 ±0.5 mils
- III. Pad Opening (min)  
90 x 90 microns  
3.5 x 3.5 mils



1. The backside of die is internally connected to V<sub>SS</sub>. It **MUST NOT** be connected to any other potential or damage may occur.
2. Double bond recommended.
3. This figure reflects the current die thickness. Please contact ISD as this thickness may change in the future.

**Table 16: ISD4003 Series Device Pin/Pad Designations,  
with Respect to Die Center ( $\mu\text{m}$ )**

Pin	Pin Name	X Axis	Y Axis
V <sub>SSA</sub>	V <sub>SS</sub> Analog Power Supply	-1898.1	-3272.4
V <sub>SSA</sub>	V <sub>SS</sub> Analog Power Supply	-1599.9	-3272.4
AUD OUT	Audio Output	281.9	-3272.4
AMCAP	AutoMute	577.3	-3272.4
ANA IN -	Inverting Analog Input	1449.3	-3272.4
ANA IN +	Noninverting Analog Input	1603.5	-3272.4
V <sub>CCA</sub> <sup>(1)</sup>	V <sub>CC</sub> Analog Power Supply	1898.7	-3272.4
V <sub>SSA</sub>	V <sub>SS</sub> Analog Power Supply	1885.2	3273.7
RAC	Row Address Clock	1483.8	3273.7
INT	Interrupt	794.8	3273.7
XCLK	External Clock Input	564.8	3273.7
V <sub>CCD2</sub>	V <sub>CC</sub> Digital Power Supply	384.9	3273.7
V <sub>CCD1</sub>	V <sub>CC</sub> Digital Power Supply	169.5	3273.7
SCLK	Slave Clock	-14.7	3273.7
SS	Slave Select	-198.1	3273.7
MOSI	Master Out Slave In	-1063.7	3273.7
MISO	Master In Slave Out	-1325.6	3273.7
V <sub>SSD1</sub>	V <sub>SS</sub> Digital Power Supply	-1665.3	3273.7
V <sub>SSD2</sub>	V <sub>SS</sub> Digital Power Supply	-1836.9	3273.7

1. Double bond recommended.

Figure 18: ISD4003 Chip Scale Package (CSP) (Z)

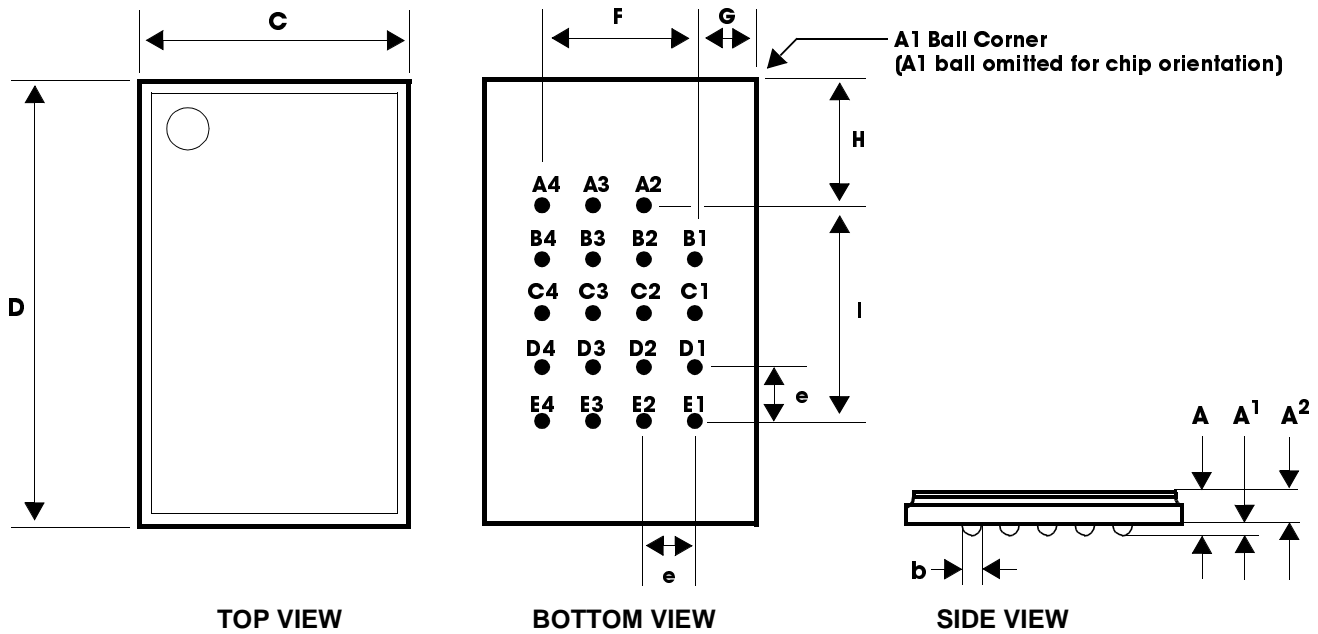


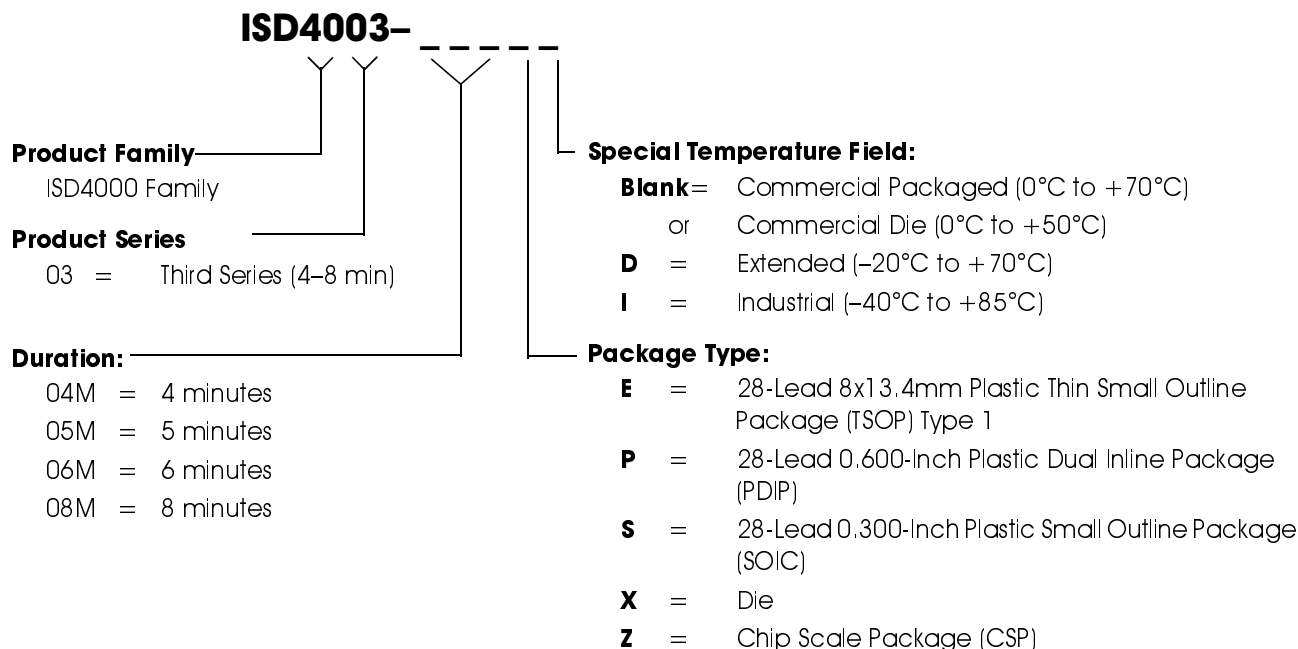
Table 17: CSP Dimensions

Symbol	Min.	Nom.	Max.
A	—	—	0.85
A <sup>1</sup>	0.15	—	—
A <sup>2</sup>	—	0.55	—
b	0.30	0.35	0.40
C	—	4.70	—
D	—	7.45	—
e	—	0.75	—
F	—	2.25	—
G	—	1.22	—
H	—	2.22	—
I	—	3.00	—

Name	Ball Location	TSOP Pin #
V <sub>SSA</sub>	A2	18
AMCAP	A3	22
ANAIN+	A4	25
V <sub>SSA</sub>	B1	17
AUDOUT	B2	20
ANAIN-	B3	24
V <sub>CCA</sub>	B4	26
V <sub>SSD1</sub>	C1	12
V <sub>SSD2</sub>	C2	N/A
V <sub>CCD2</sub>	C3	N/A
V <sub>SSA</sub>	C4	1
MOSI	D1	10
SCLK	D2	8
XCLK	D3	6
RAC	D4	2
MISO	E1	11
SS	E2	9
V <sub>CCD1</sub>	E3	7
INT	E4	5

## ORDERING INFORMATION

### Product Number Descriptor Key



When ordering ISD4003 series devices, please refer to the following valid part numbers.

Part Number	Part Number	Part Number	Part Number
ISD4003-04ME	ISD4003-05ME	ISD4003-06ME	ISD4003-08ME
ISD4003-04MED	ISD4003-05MED	ISD4003-06MED	ISD4003-08MED
ISD4003-04MEI	ISD4003-05MEI	ISD4003-06MEI	ISD4003-08MEI
ISD4003-04MP	ISD4003-05MP	ISD4003-06MP	ISD4003-08MP
ISD4003-04MS	ISD4003-05MS	ISD4003-06MS	ISD4003-08MS
ISD4003-04MSI	ISD4003-05MSI	ISD4003-06MSI	ISD4003-08MSI
ISD4003-04MX	ISD4003-05MX	ISD4003-06MX	ISD4003-08MX
ISD4003-04MZ	ISD4003-05MZ	ISD4003-06MZ	ISD4003-08MZ
ISD4003-04MZD	ISD4003-05MZD	ISD4003-06MZD	ISD4003-08MZD
ISD4003-04MZI	ISD4003-05MZI	ISD4003-06MZI	ISD4003-08MZI

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